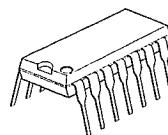


QUAD OPERATIONAL AMPLIFIER

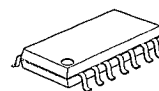
■ GENERAL DESCRIPTION

The NJM2060 integrated circuit is a high-gain, wide-bandwidth, quad operational amplifier capable of driving 20V peak-to-peak into 400Ω loads. The NJM2060 combines many of the features of the NJM2058 as well as providing the capability of wider bandwidth, and higher slew rate make the NJM2060 ideal for active filters, data and telecommunications, and many instrumentation applications. The availability of the NJM2060 in the surface mounted micro-package allows the NJM2060 to be used in critical applications requiring very high packing densities. Each amplifier of the NJM2060 has the same electrical characteristic of the NJM4560.

■ PACKAGE OUTLINE



NJM2060D



NJM2060M

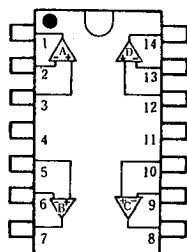


NJM2060V

■ FEATURES

- Operating Voltage $(\pm 4V \sim \pm 18V)$
- Low Noise Voltage (RIAA 1.2 μV_{rms} typ.)
- Slew Rate (4V/ μs typ.)
- Unity Gain Bandwidth (10MHz typ.)
- High Output Current (25mA)
- Package Outline DIP14, DMP14, SSOP14
- Bipolar Technology

■ PIN CONFIGURATION

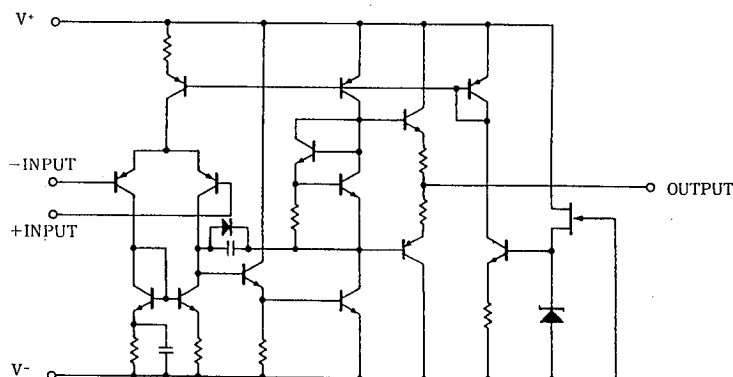


NJM2060D
NJM2060M
NJM2060V

PIN FUNCTION

- | | |
|-------------------|--------------------|
| 1. A OUTPUT | 8. C OUTPUT |
| 2. A-INPUT | 9. C-INPUT |
| 3. A+INPUT | 10. C+INPUT |
| 4. V ⁺ | 11. V ⁻ |
| 5. B+INPUT | 12. D+INPUT |
| 6. B-INPUT | 13. D-INPUT |
| 7. B OUTPUT | 14. D OUTPUT |

■ EQUIVALENT CIRCUIT (1/4 Shown)



■ ABSOLUTE MAXIMUM RATINGS

(Ta=25°C)

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	V ⁺ /V ⁻	±18	V
Differential Input Voltage	V _{ID}	±30	V
Input Voltage	V _{IC}	±15 (note 1)	V
Power Dissipation	P _D	(DIP14) 700	mW
		(DIM14) 700 (note 2)	mW
		(SSOP14) 300	mW
Operating Temperature Range	T _{opr}	-20~+75	°C
Storage Temperature Range	T _{stg}	-40~+125	°C

(note 1) For supply voltage less than ±15V, the absolute maximum input voltage is equal to the supply voltage.

(note 2) At on PC board

■ ELECTRICAL CHARACTERISTICS

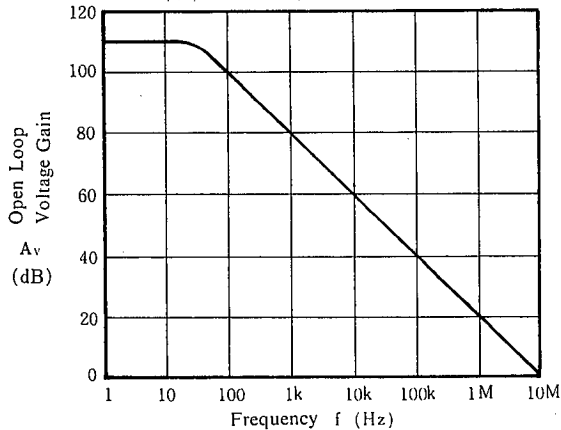
(Ta=25°C, V⁺=15V, V⁻= -15V)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Input Offset Voltage	V _{IO}	R _S ≤ 10kΩ	—	0.5	6	mV
Input Offset Current	I _{IO}		—	5	200	nA
Input Bias Current	I _B		—	40	500	nA
Input Resistance	R _{IN}		100	500	—	kΩ
Large Signal Voltage Gain	A _V	R _L ≥ 2kΩ, V _O = ±10V	86	100	—	dB
Maximum Output Voltage Swing 1	V _{OM1}	R _L ≥ 2kΩ	±12	±14	—	V
Maximum Output Voltage Swing 2	V _{OM2}	I _O = 25mA	±10	±11.5	—	V
Input Common Mode Voltage Range	V _{ICM}		±12	±14	—	V
Common Mode Rejection Ratio	CMR	R _S ≤ 10kΩ	70	90	—	dB
Supply Voltage Rejection Ratio	SVR	R _S ≤ 10kΩ	76	90	—	dB
Operating Current	I _{CC}		—	9	14	mA
Slew Rate	SR		—	4	—	V/μs
Gain Bandwidth Product	GB		—	10	—	MHz
Equivalent Input Noise Voltage	V _{NI}	RIAA R _S = 2.2kΩ, 30kHz L.P.F.	—	1.2	—	μVrms

■ TYPICAL CHARACTERISTICS

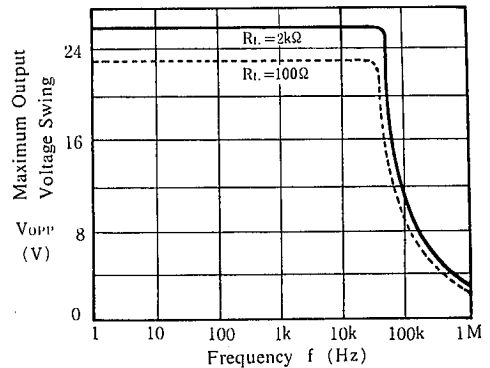
Open Loop Voltage Gain
vs. Frequency

($V^+/V^- = \pm 15V$, $R_L = 2k\Omega$, $T_a = 25^\circ C$)



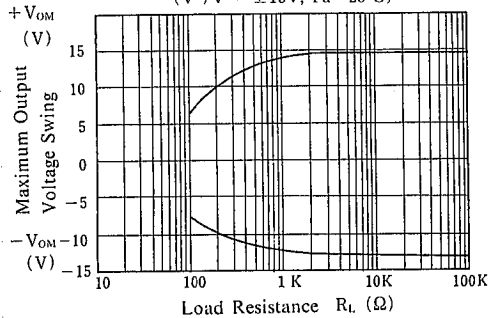
Maximum Output Voltage Swing
vs. Frequency

($V^+/V^- = \pm 15V$, $T_a = 25^\circ C$)



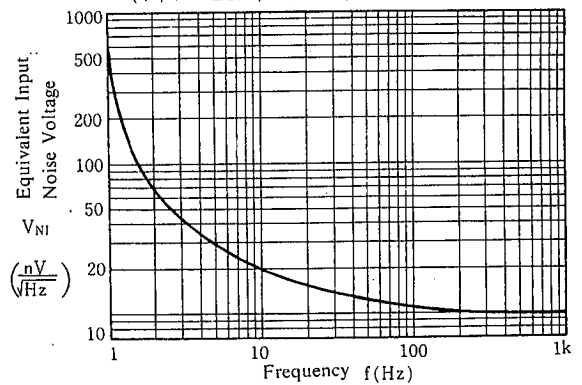
Maximum Output Voltage Swing
vs. Load Resistance

($V^+/V^- = \pm 15V$, $T_a = 25^\circ C$)



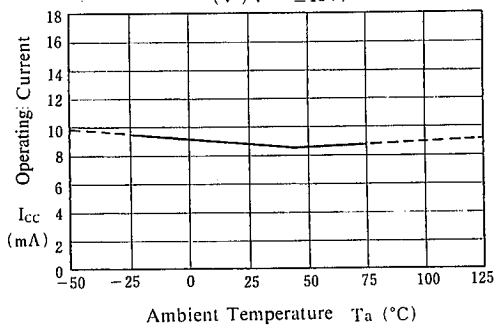
Equivalent Input Noise Voltage
vs. Frequency

($V^+/V^- = \pm 15V$, $R_S = 50\Omega$, $A_v = 60dB$, $T_a = 25^\circ C$)



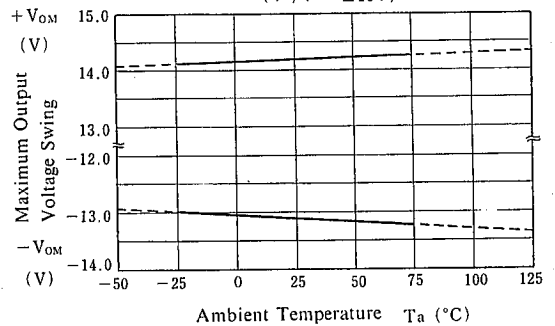
Operating Current vs. Temperature

($V^+/V^- = \pm 15V$)

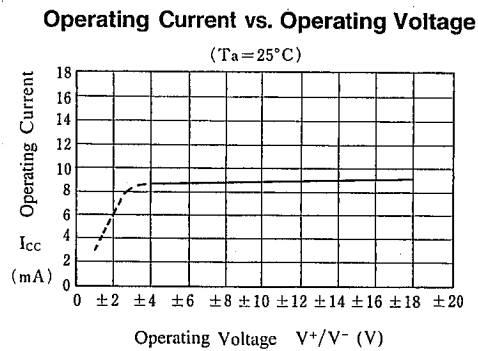
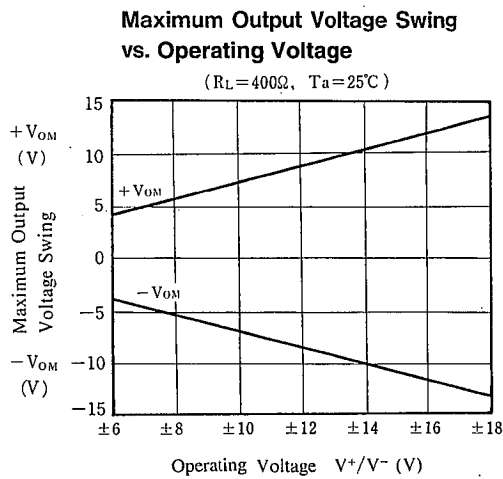
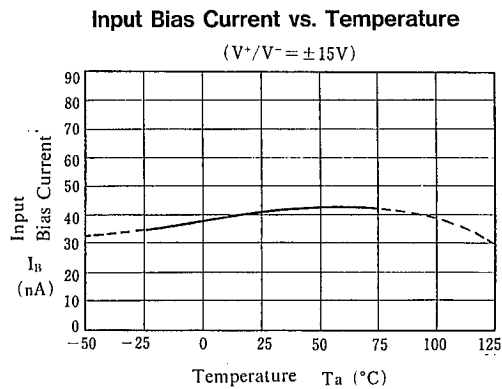
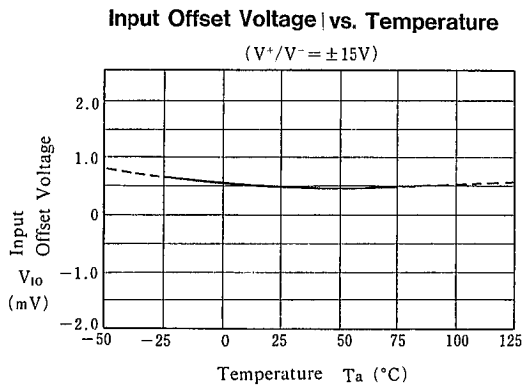


Maximum Output Voltage Swing
vs. Temperature

($V^+/V^- = \pm 15V$)



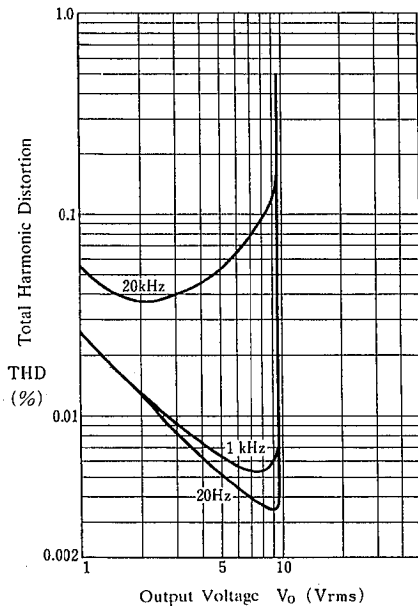
■ TYPICAL CHARACTERISTICS



■ TYPICAL CHARACTERISTICS

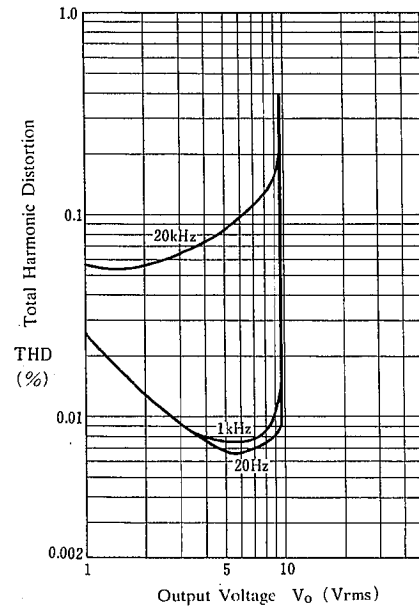
Total Harmonic Distortion

($V^+/V^- = \pm 15V$, Gain = 40dB, $R_L = 10k\Omega$,
 $T_a = 25^\circ C$)



Total Harmonic Distortion

($V^+/V^- = \pm 15V$, Gain = 40dB, $R_L = 2k\Omega$,
 $T_a = 25^\circ C$)



MEMO

[CAUTION]

The specifications on this databook are only given for information, without any guarantee as regards either mistakes or omissions. The application circuits in this databook are described only to show representative usages of the product and not intended for the guarantee or permission of any right including the industrial rights.